

## LOW DROPOUT VOLTAGE REGULATOR

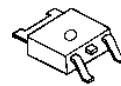
### ■ GENERAL DESCRIPTION

The NJM2835 is a 500mA output low dropout voltage regulator.

Advanced Bipolar technology achieves low noise, high ripple rejection and high supply voltage.

2.1V to 15.5V output voltage range, 2.2 $\mu$ F small decoupling capacitor, built-in noise bypass capacitor make the NJM2835 suitable for various applications.

### ■ PACKAGE OUTLINE

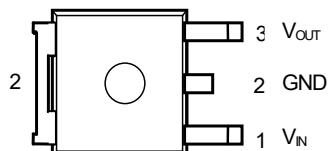


NJM2835DL1

### ■ FEATURES

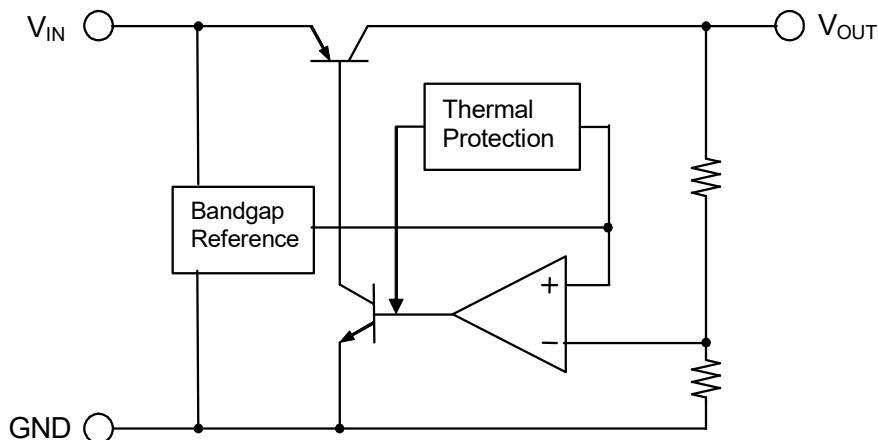
- Output voltage options available 2.1 ~ 15.5V
- High Ripple Rejection 75dB typ. ( $f=1\text{kHz}, V_o=3\text{V}$  Version)
- Output Noise Voltage  $V_{no}=45\mu\text{VRms}$  typ.
- Output capacitor with 2.2 $\mu$ F ceramic capacitor ( $V_o \geq 5.1\text{V}$ )
- Output Current  $I_o(\text{max.})=500\text{mA}$
- High Precision Output  $V_o \pm 1.0\%$
- Low Dropout Voltage 0.18V typ. ( $I_o=300\text{mA}$ )
- Internal Thermal Overload Protection
- Internal Over Current Protection
- Bipolar Technology
- Package Outline TO-252-3

### ■ PIN CONFIGURATION



NJM2835DL1

### ■ BLOCK DIAGRAM



## ■ OUTPUT VOLTAGE RANK LIST

The WHITE column shows applicable Voltage Rank(s)

Device Name	Vout	Device Name	Vout	Device Name	Vout
NJM2835DL1-21	2.1V	NJM2835DL1-36	3.6V	NJM2835DL1-08	8.0V
NJM2835DL1-22	2.2V	NJM2835DL1-37	3.7V	NJM2835DL1-85	8.5V
NJM2835DL1-23	2.3V	NJM2835DL1-38	3.8V	NJM2835DL1-09	9.0V
NJM2835DL1-24	2.4V	NJM2835DL1-39	3.9V	NJM2835DL1-10	10.0V
NJM2835DL1-25	2.5V	NJM2835DL1-04	4.0V	NJM2835DL1-12	12.0V
NJM2835DL1-26	2.6V	NJM2835DL1-41	4.1V	NJM2835DL1-15	15.0V
NJM2835DL1-27	2.7V	NJM2835DL1-42	4.2V		
NJM2835DL1-28	2.8V	NJM2835DL1-43	4.3V		
NJM2835DL1-29	2.9V	NJM2835DL1-44	4.4V		
NJM2835DL1-03	3.0V	NJM2835DL1-45	4.5V		
NJM2835DL1-31	3.1V	NJM2835DL1-46	4.6V		
NJM2835DL1-32	3.2V	NJM2835DL1-47	4.7V		
NJM2835DL1-33	3.3V	NJM2835DL1-48	4.8V		
NJM2835DL1-34	3.4V	NJM2835DL1-49	4.9V		
NJM2835DL1-35	3.5V	NJM2835DL1-05	5.0V		

## ■ ABSOLUTE MAXIMUM RATINGS

(Ta=25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Input Voltage	V <sub>IN</sub>	+20	V
Power Dissipation	P <sub>D</sub>	1190(*1) 3125(*2)	mW
Operating Temperature	T <sub>opr</sub>	-40 ~ +85	°C
Storage Temperature	T <sub>tsg</sub>	-40 ~ +150	°C

(\*1): Mounted on glass epoxy board. (76.2 × 114.3 × 1.6mm:based on EIA/JDEC standard size, 2Layers, Cu area 100mm<sup>2</sup>)

(\*2): Mounted on glass epoxy board. (76.2 × 114.3 × 1.6mm:based on EIA/JDEC standard, 4Layers)

(For 4Layers: Applying 74.2 × 74.2mm inner Cu area and a thermal via hole to a board based on JEDEC standard JESD51-5)

## ■ ELECTRICAL CHARACTERISTICS

V<sub>IN</sub>= Vo+1V, C<sub>IN</sub>=0.33μF, Co=2.2μF (2.9V<Vo≤5V:Co=4.7μF, Vo≤2.9V:Co=10μF), Ta=25°C

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT	
Output Voltage	Vo	Io=30mA	-1.0%	-	+1.0%	V	
Quiescent Current	I <sub>Q</sub>	Io=0mA	Vo≤5V Version	-	200	300	μA
			5V<Vo≤10V Version	-	215	315	μA
			10V<Vo≤15V Version	-	230	330	μA
Output Current	Io	Vo-0.3V	500	650	-	mA	
Line Regulation	ΔVo/ΔV <sub>IN</sub>	V <sub>IN</sub> =Vo+1V ~ Vo+6V(Vo≤12V), V <sub>IN</sub> =Vo+1V ~ 18V(Vo>12V), Io=30mA	-	-	0.10	%/V	
Load Regulation	ΔVo/ΔIo	Io=0 ~ 500mA	-	-	0.007	%/mA	
Dropout Voltage(*3)	ΔV <sub>IO</sub>	Io=300mA	-	0.18	0.28	V	
Ripple Rejection	RR	ein=200mVrms,f=1kHz,Io=10mA Vo=3V Version	-	75	-	dB	
Average Temperature Coefficient of Output Voltage	ΔVo/ΔTa	Ta=0 ~ 85°C, Io=10mA	-	± 50	-	ppm/°C	
Output Noise Voltage	V <sub>NO</sub>	f=10Hz ~ 80kHz, Io=10mA, Vo=3V Version	-	45	-	μVrms	
Input Voltage	V <sub>IN</sub>		-	-	18	V	

(\*3): The above specification is a common specification for all output voltages.

Therefore, it may be different from the individual specification for a specific output voltage.

## ■ THERMAL CHARACTERISTICS

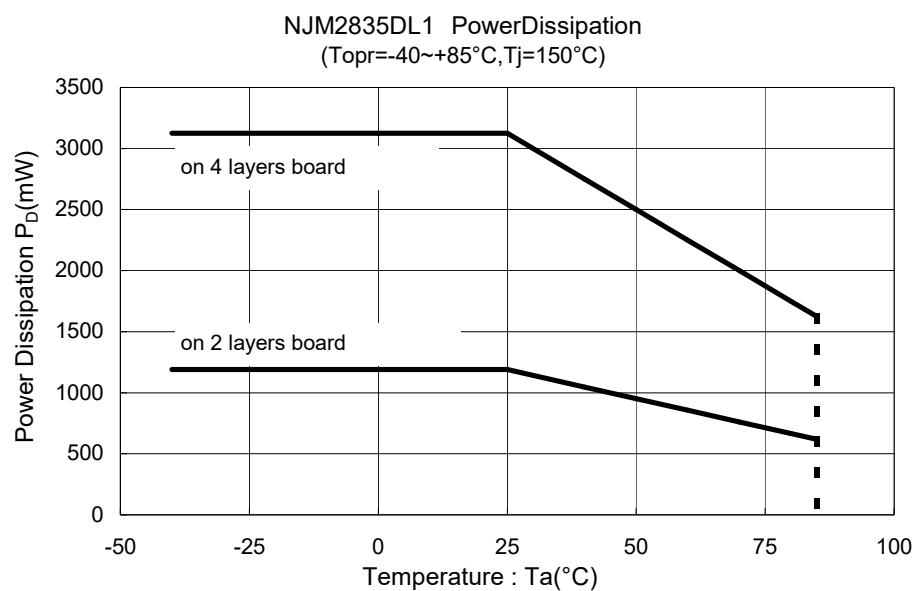
PARAMETER	SYMBOL	VALUE	UNIT
Junction-to-Ambient thermal resistance	$\theta_{ja}$	105 (*4) 40 (*5)	°C/W
Junction-to-Top of package characterization parameter	$\psi_{jt}$	17 (*4) 12 (*5)	°C/W

(\*4): Mounted on glass epoxy board. (76.2 × 114.3 × 1.6mm:based on EIA/JDEC standard size, 2Layers, Cu area 100mm<sup>2</sup>)

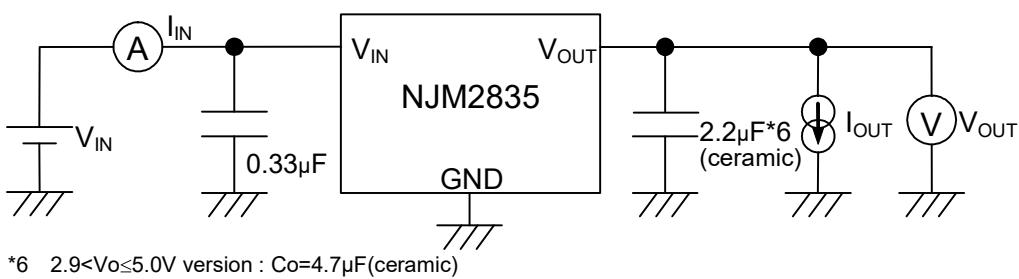
(\*5): Mounted on glass epoxy board. (76.2 × 114.3 × 1.6mm:based on EIA/JDEC standard, 4Layers)

(For 4Layers: Applying 74.2 × 74.2mm inner Cu area and a thermal via hole to a board based on JEDEC standard JESD51-5)

## ■ POWER DISSIPATION vs. AMBIENT TEMPERATURE



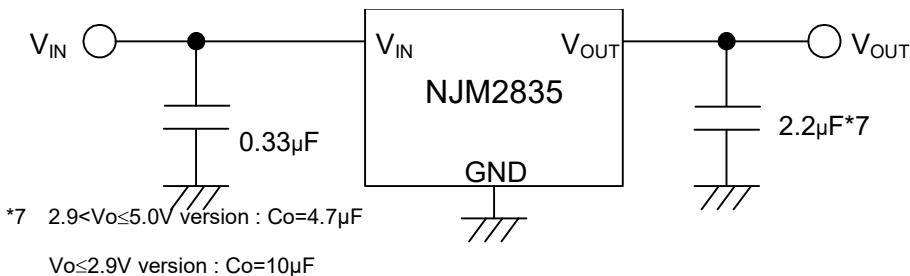
## ■ TEST CIRCUIT



\*6  $2.9 < V_{OUT} \leq 5.0V$  version :  $C_O = 4.7\mu F$  (ceramic)

$V_{OUT} \leq 2.9V$  version :  $C_O = 10\mu F$  (ceramic)

## ■ TYPICAL APPLICATION



\*7  $2.9 < V_{OUT} \leq 5.0V$  version :  $C_O = 4.7\mu F$

$V_{OUT} \leq 2.9V$  version :  $C_O = 10\mu F$

### \*Input Capacitor $C_{IN}$

Input Capacitor  $C_{IN}$  is required to prevent oscillation and reduce power supply ripple for applications when high power supply impedance or a long power supply line.

Therefore, use the recommended  $C_{IN}$  value (refer to conditions of ELECTRIC CHARACTERISTIC) or larger and should connect between GND and  $V_{IN}$  as shortest path as possible to avoid the problem.

### \*Output Capacitor $C_O$

The output capacitor  $C_O$  will be required for a phase compensation of the internal error amplifier.

The capacitance and the equivalent series resistance (ESR) influence to stable operation of the regulator.

Use of a smaller  $C_O$  may cause excess an output noise or an oscillation of the regulator due to lack of the phase compensation.

On the other hand, use of a larger  $C_O$  reduces an output noise and a ripple output, and also improves an output transient response when load rapidly changes.

Therefore, use the recommended  $C_O$  value (refer to conditions of ELECTRIC CHARACTERISTIC) or larger and should connect between GND and  $V_{OUT}$  as shortest path as possible for stable operation.

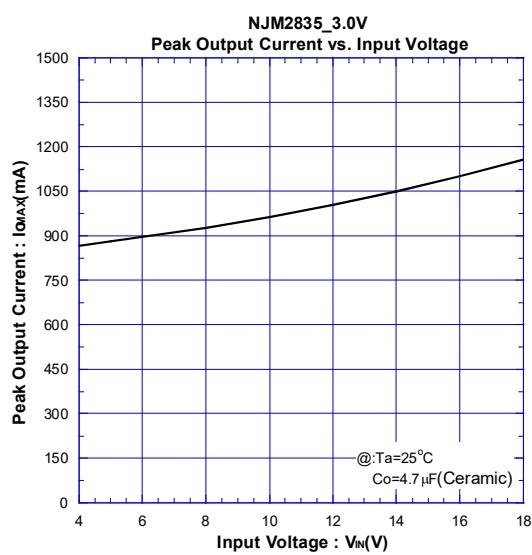
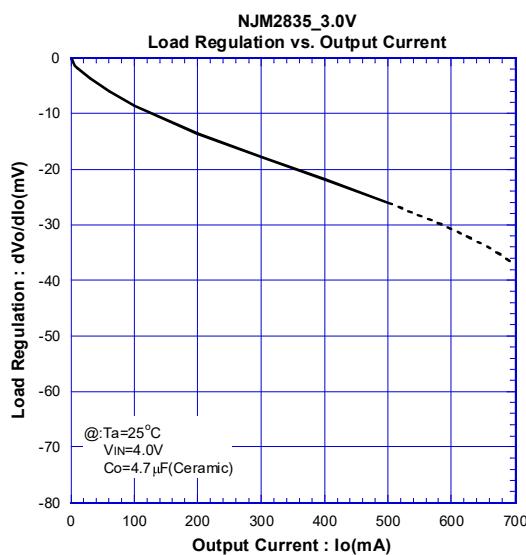
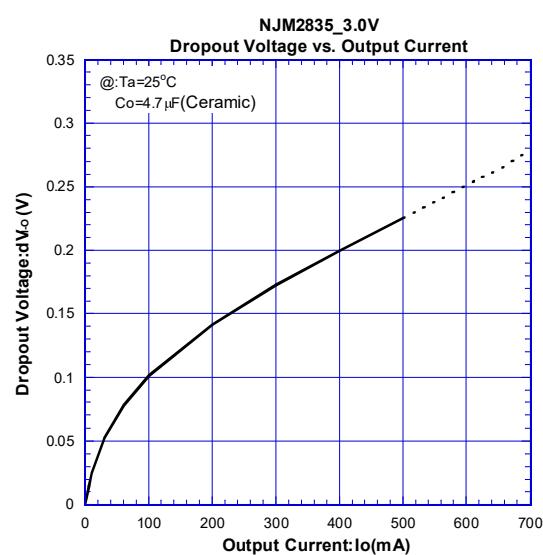
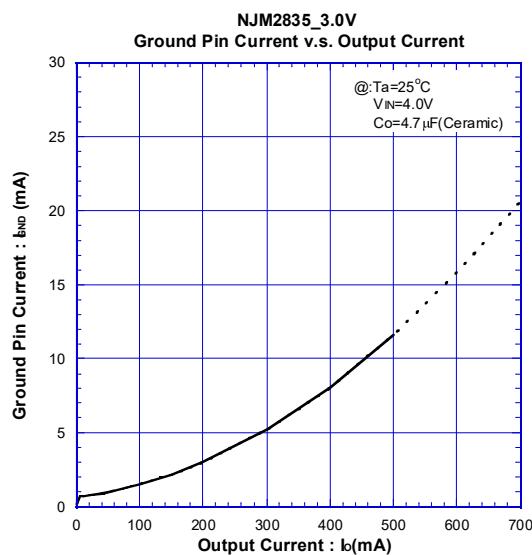
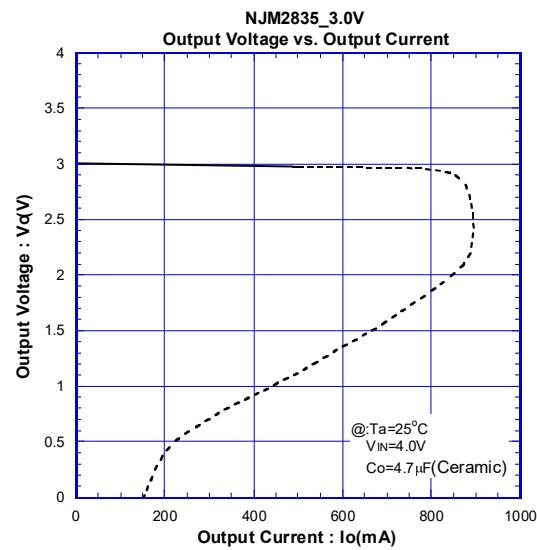
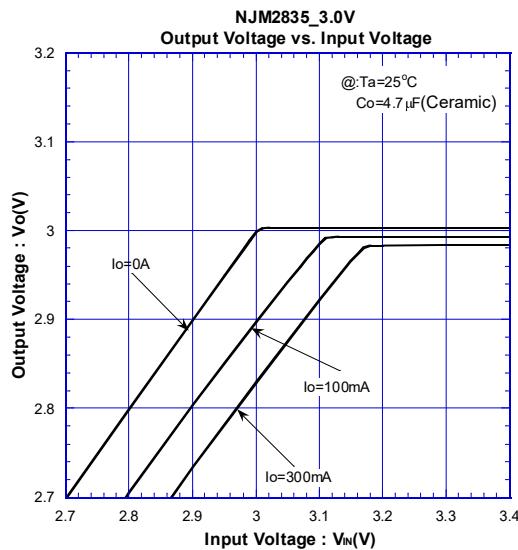
The recommended capacitance depends on the output voltage rank. Especially, a low voltage regulator requires larger  $C_O$  value.

In addition, you should consider varied characteristics of capacitor (a frequency characteristic, a temperature characteristic, a DC bias characteristic and so on) and unevenness peculiar to a capacitor supplier enough.

When selecting  $C_O$ , recommend that have withstand voltage margin against an output voltage and superior temperature characteristic.

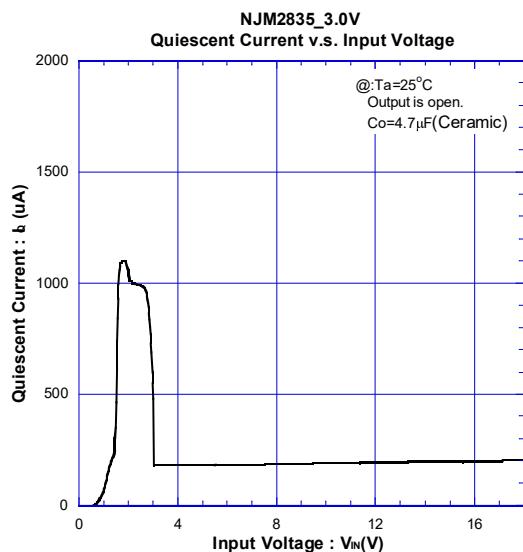
## ■ TYPICAL CHARACTERISTICS

### • DC CHARACTERISTICS (3V Version)

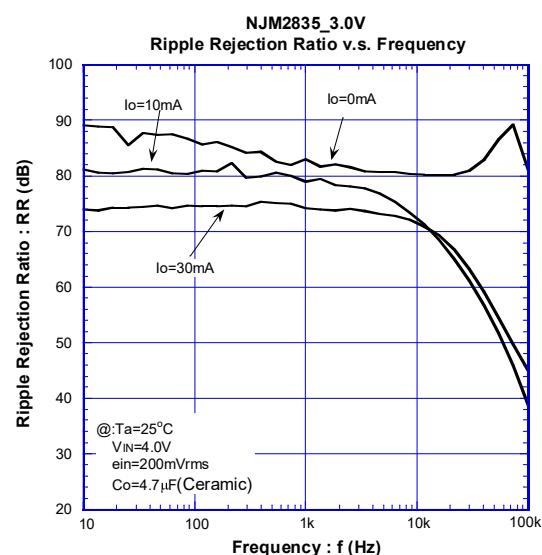
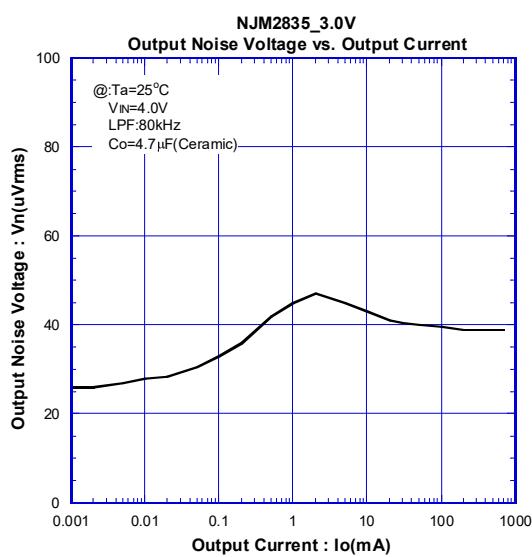


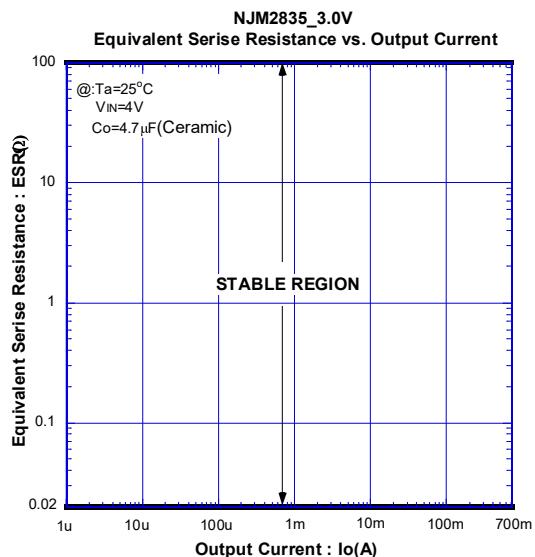
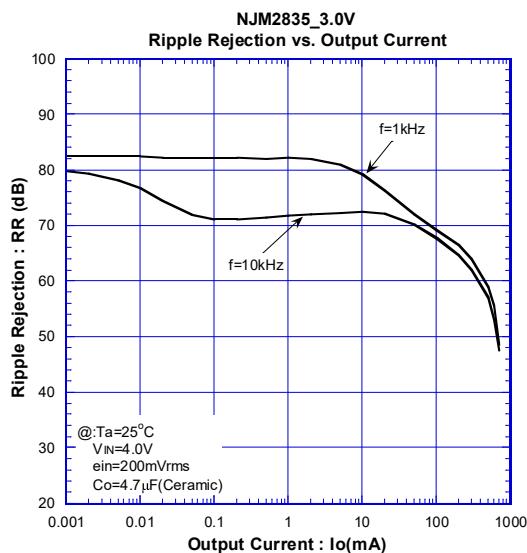
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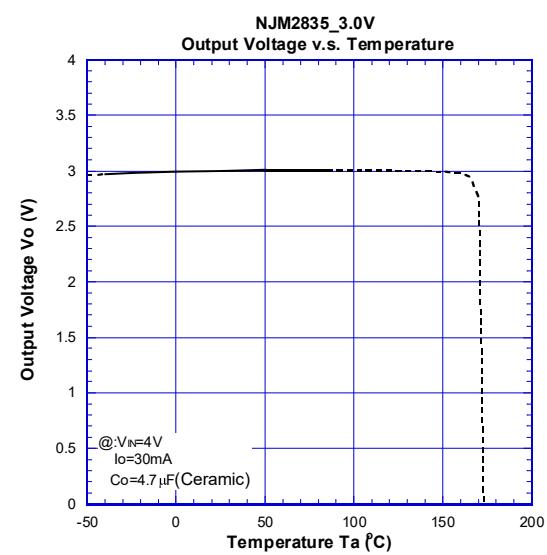
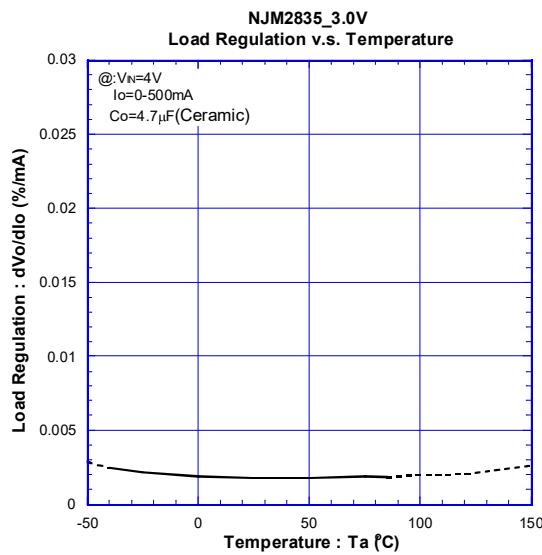
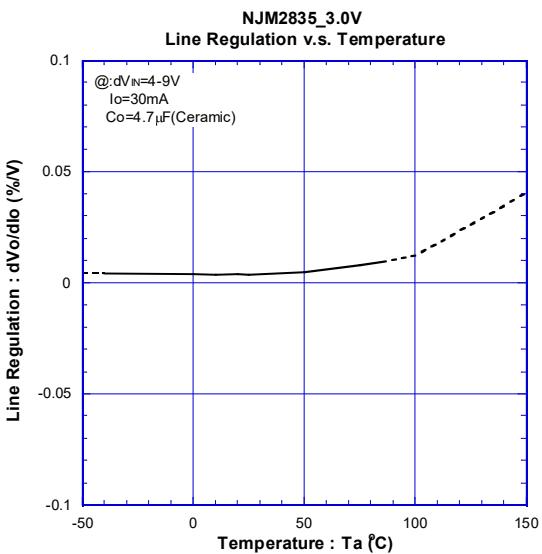
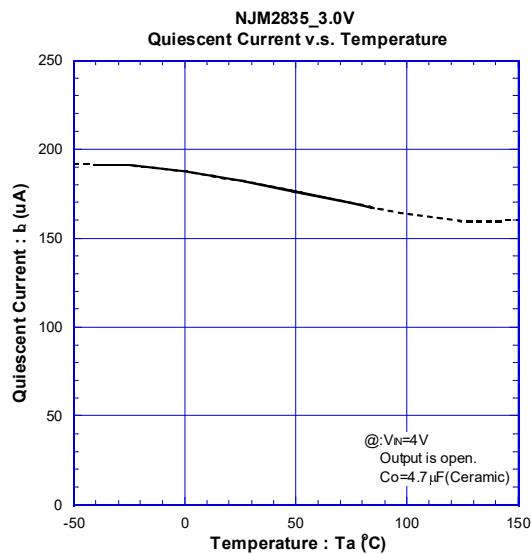
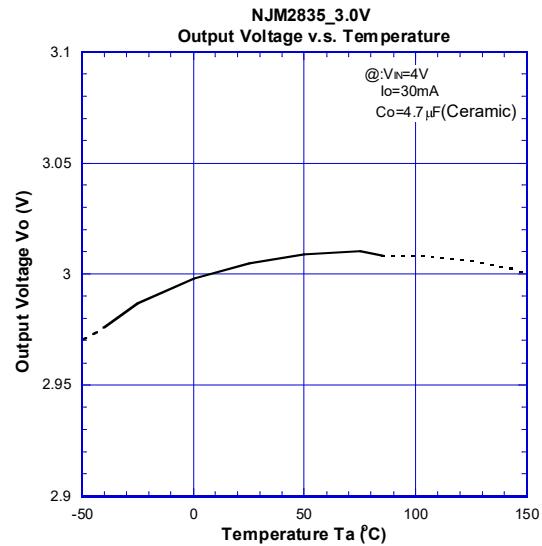
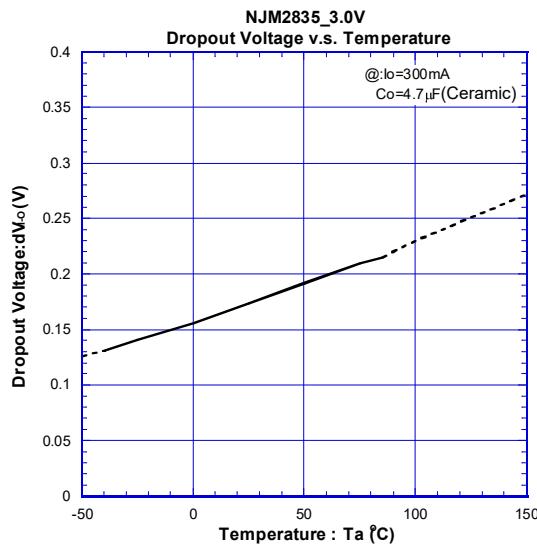
### • AC CHARACTERISTICS (3V Version)





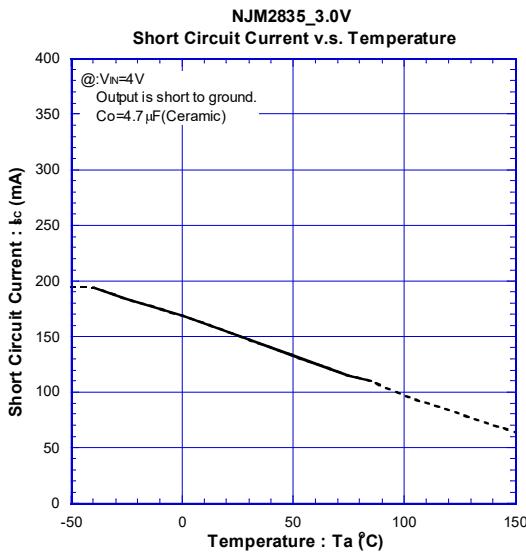
## ■ TYPICAL CHARACTERISTICS

### ● TEMPERATURE CHARACTERISTICS (3V Version)



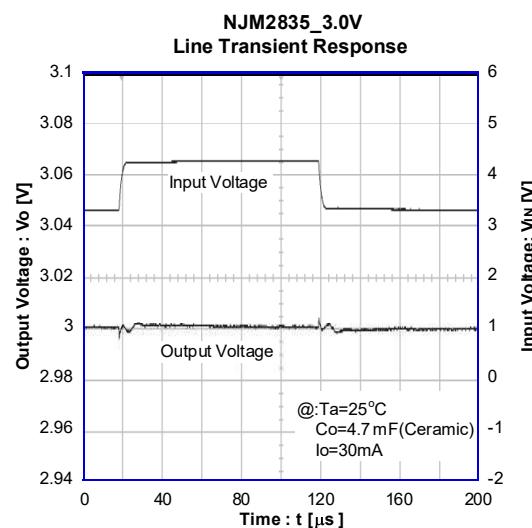
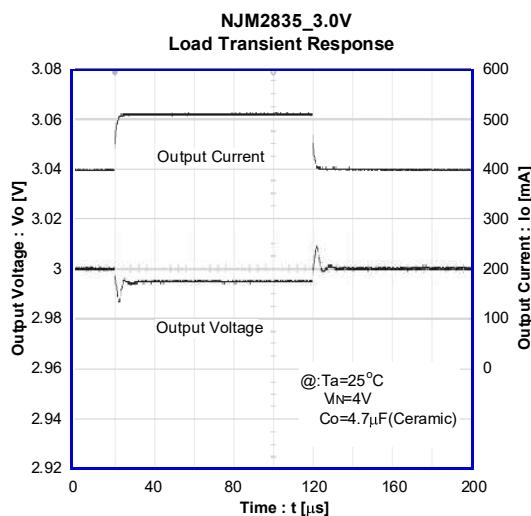
## ■ TYPICAL CHARACTERISTICS

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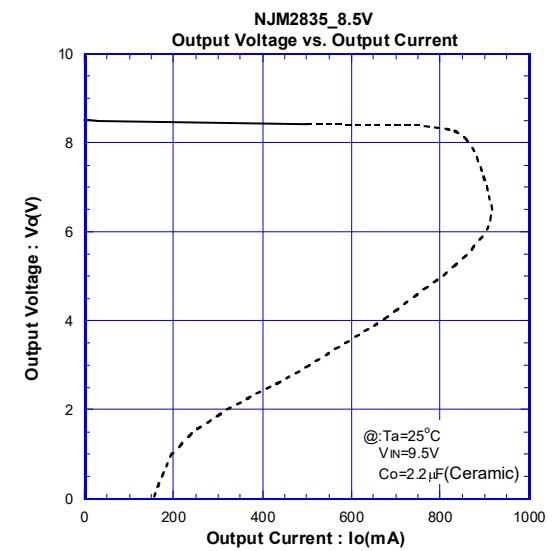
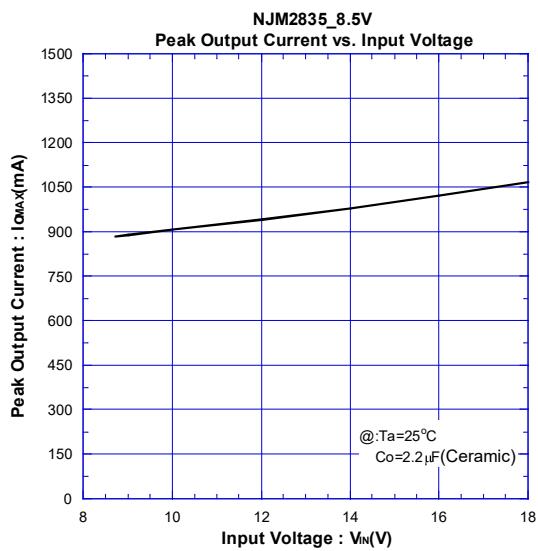
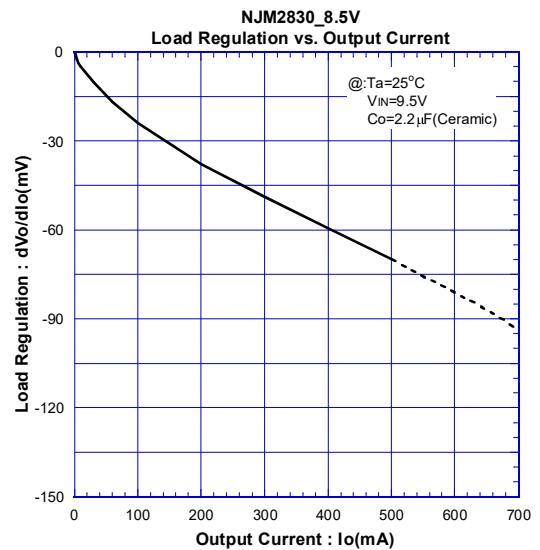
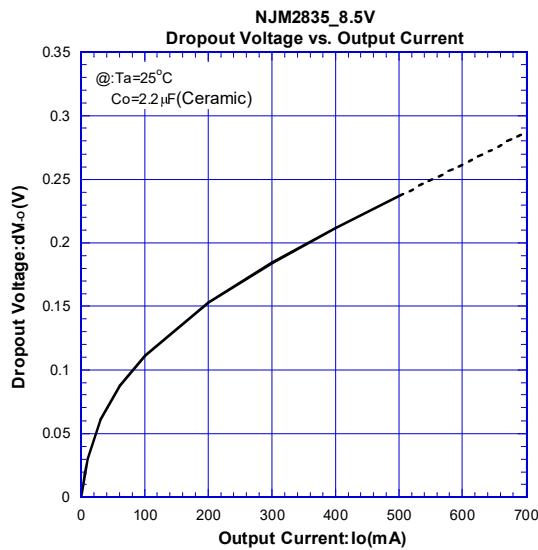
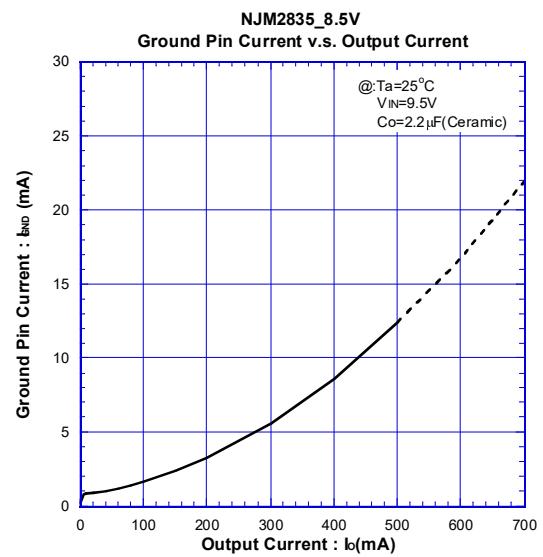
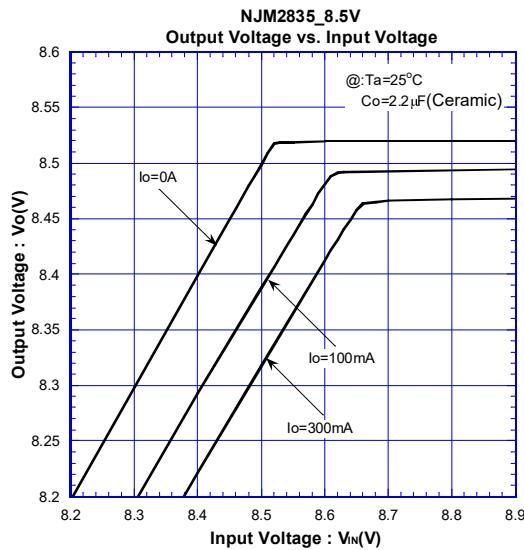
## ■ TYPICAL CHARACTERISTICS

### • TRANSIENT RESPONSE (3V Version)



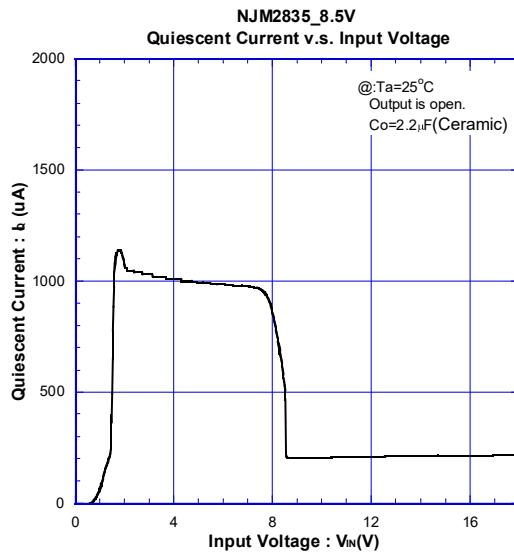
## ■ TYPICAL CHARACTERISTICS

### • DC CHARACTERISTICS (8.5V Version)

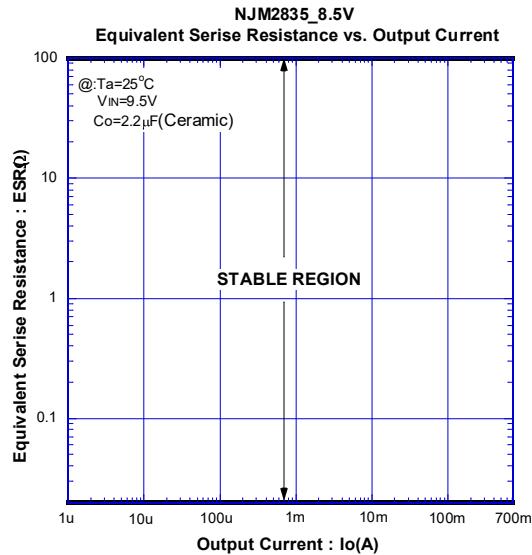
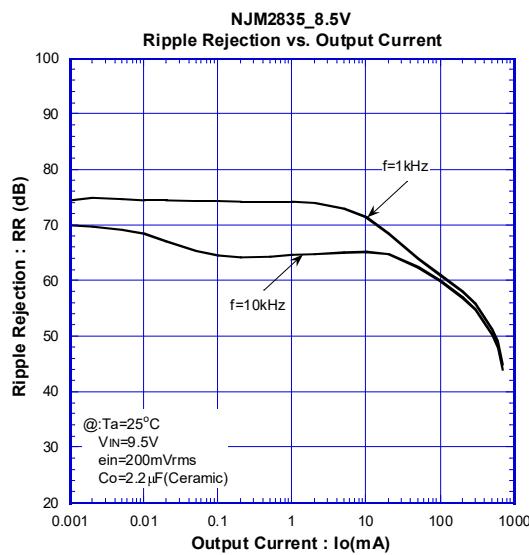
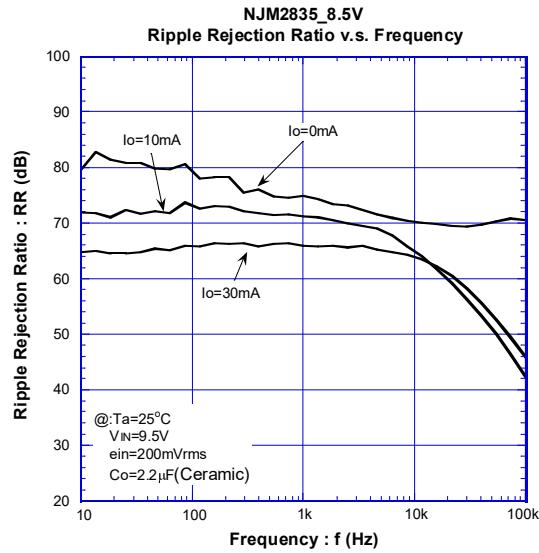
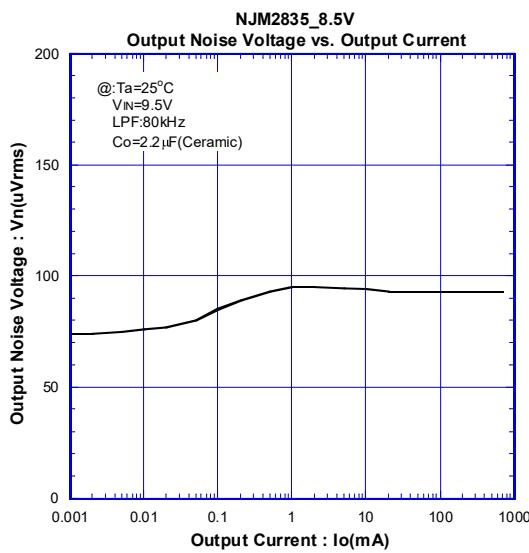


## ■ TYPICAL CHARACTERISTICS

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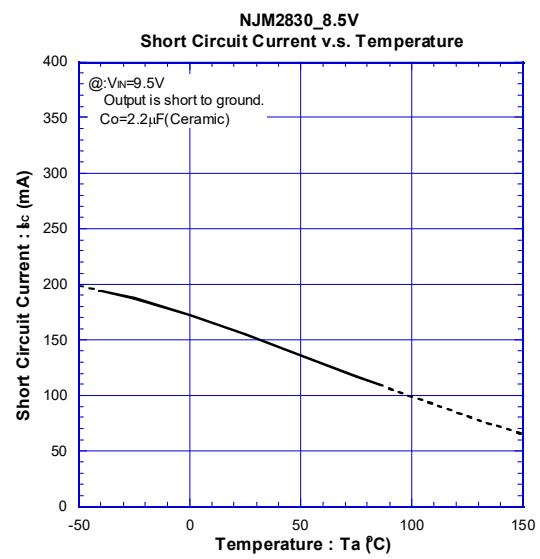
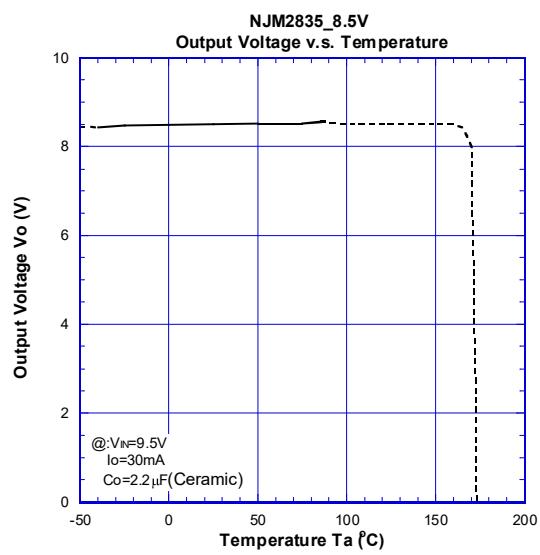
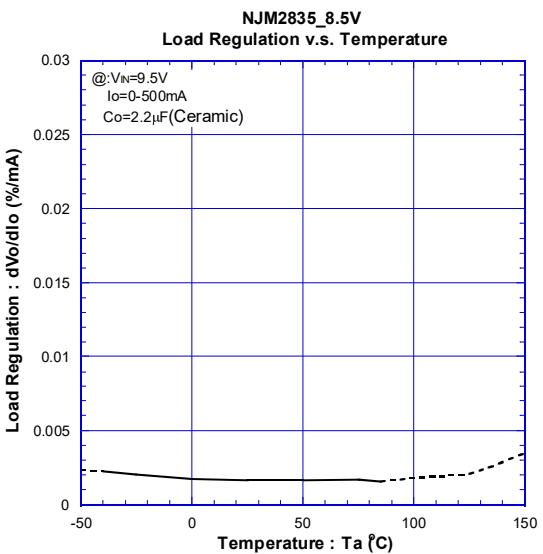
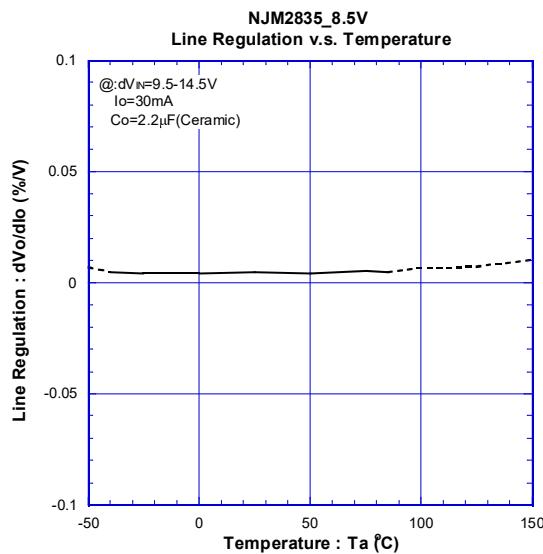
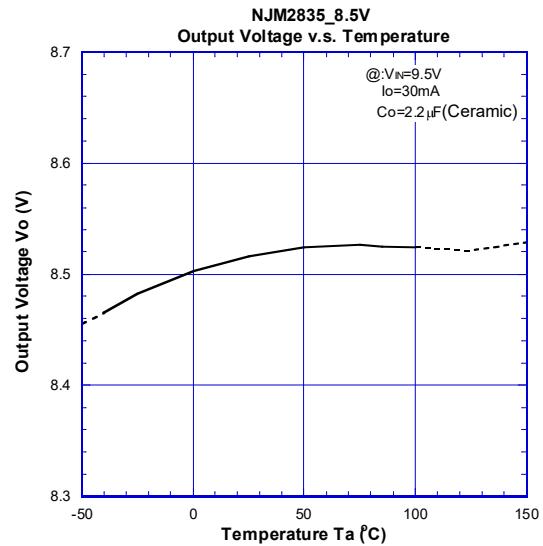
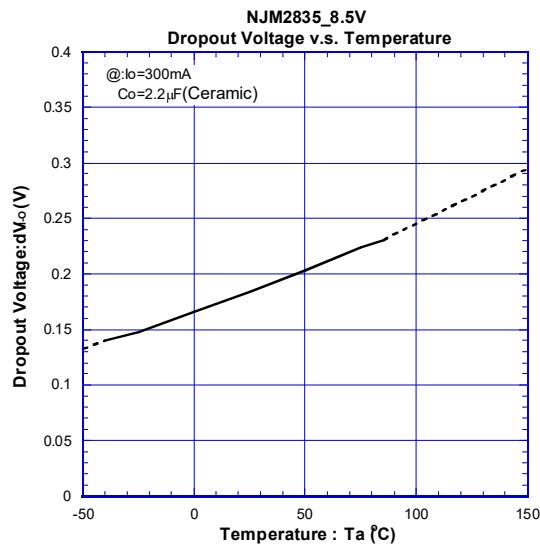


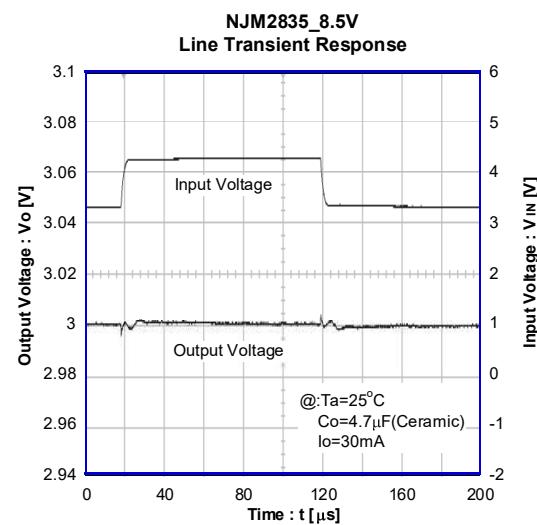
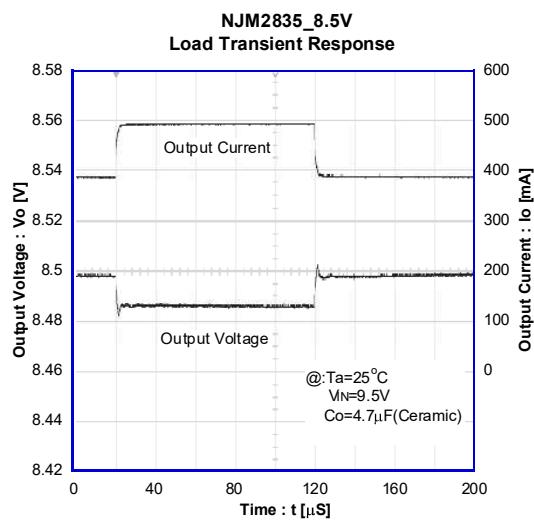
### • AC CHARACTERISTICS (8.5V Version)



## ■ TYPICAL CHARACTERISTICS

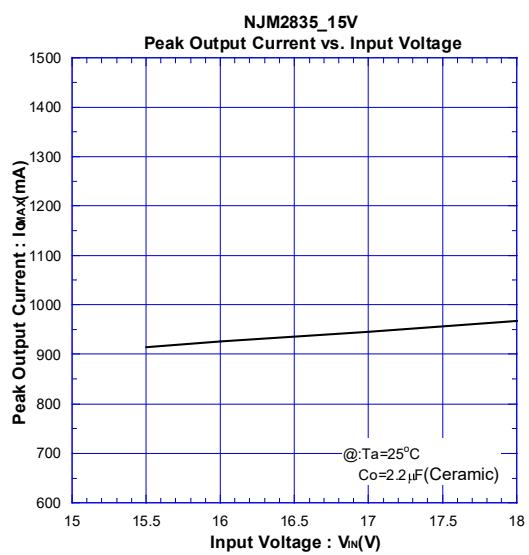
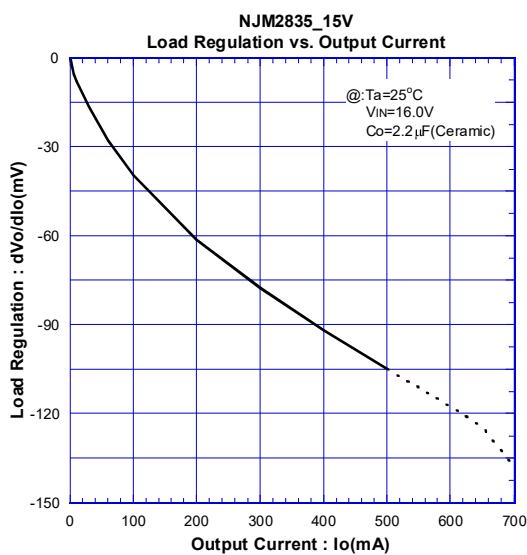
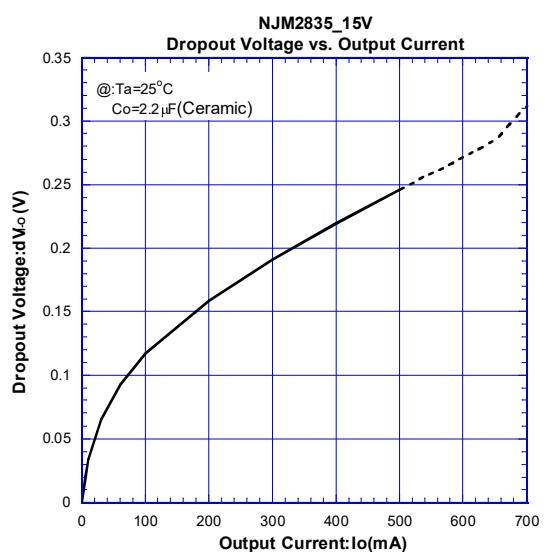
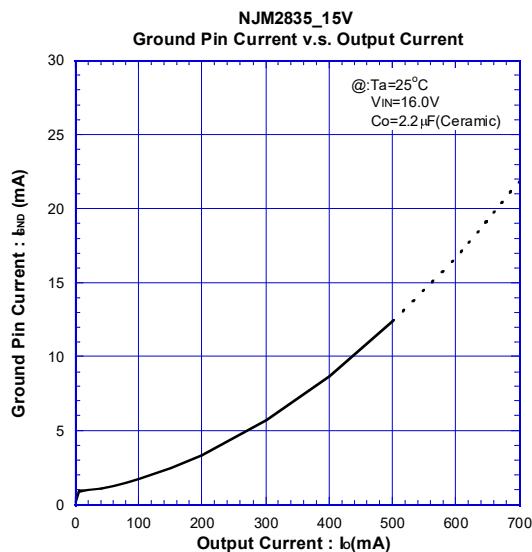
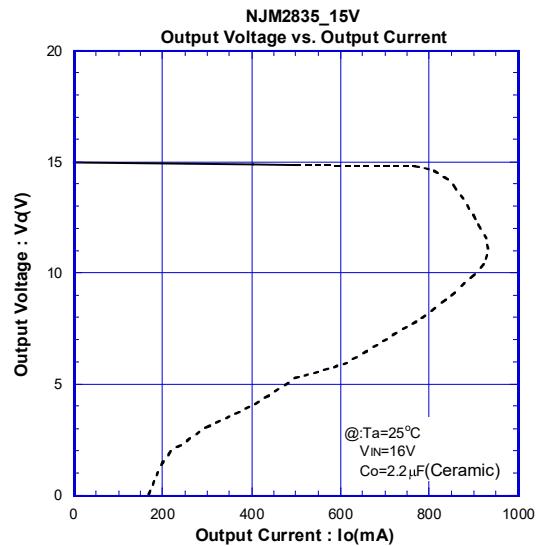
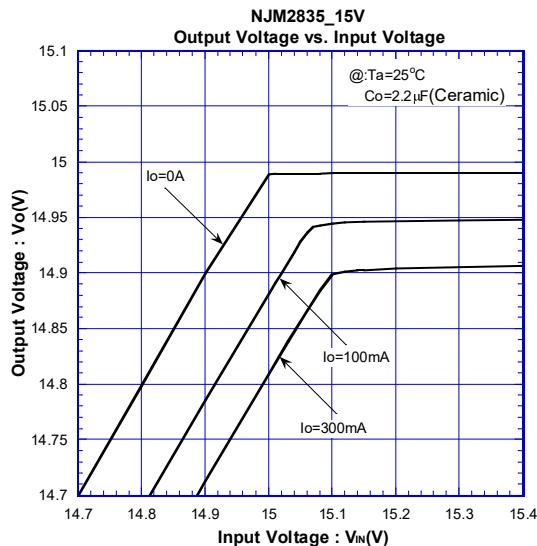
### • TEMPERATURE CHARACTERISTICS (8.5V Version)



**■ TYPICAL CHARACTERISTICS****● TRANSIENT RESPONSE (8.5V Version)**

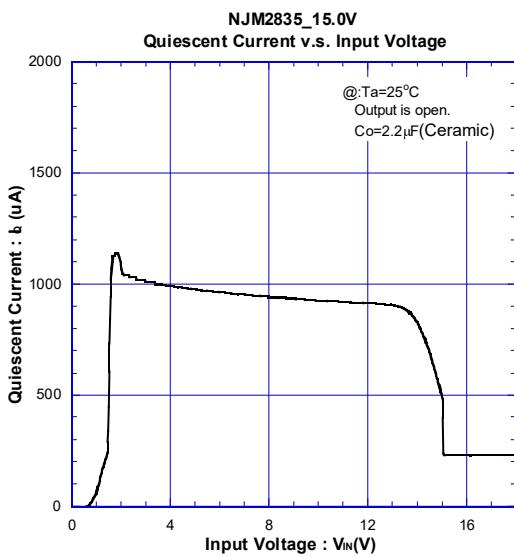
## ■ TYPICAL CHARACTERISTICS

### • DC CHARACTERISTICS (15V Version)

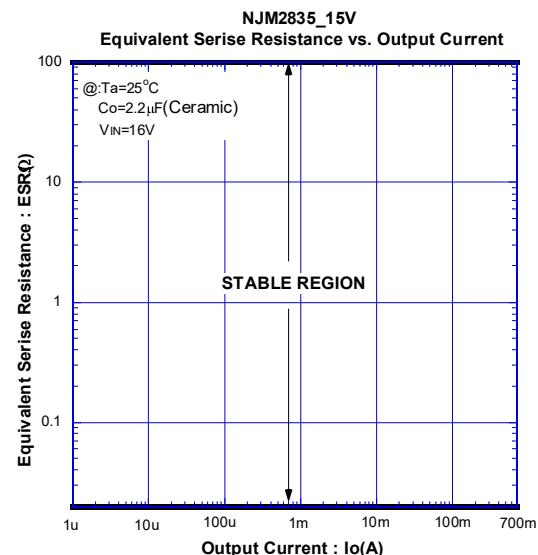
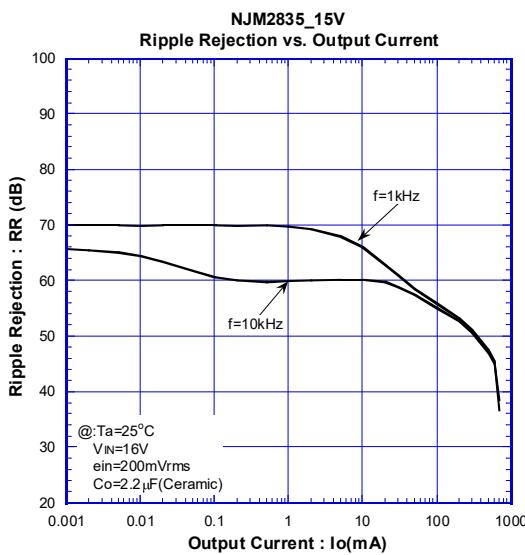
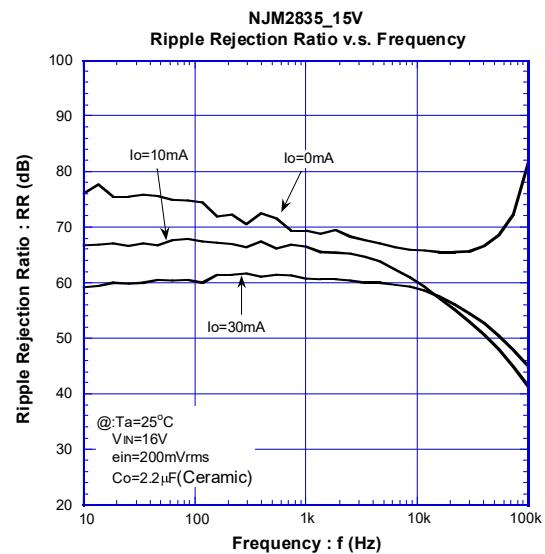
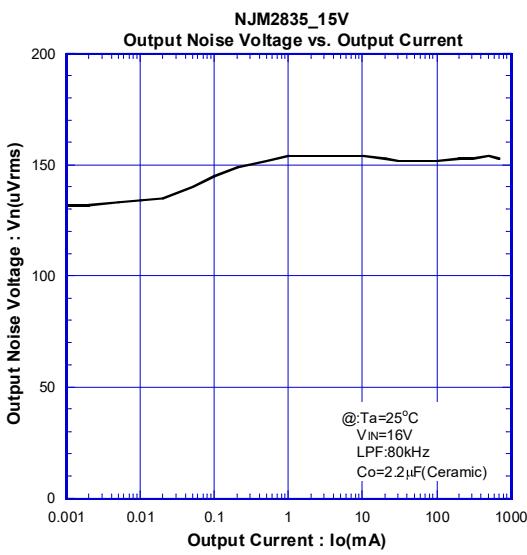


## ■ TYPICAL CHARACTERISTICS

### • DC CHARACTERISTICS (15V Version)

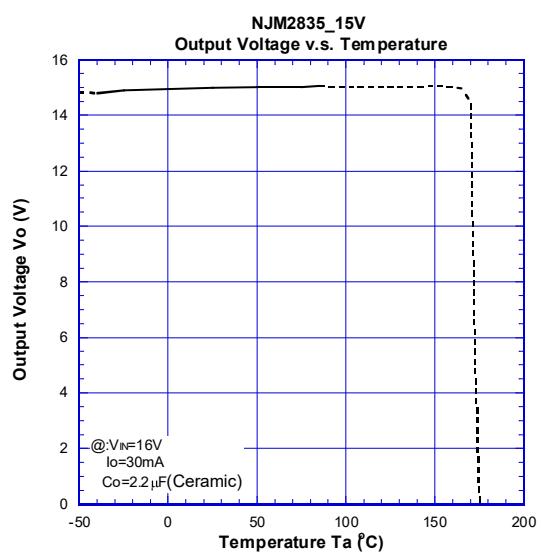
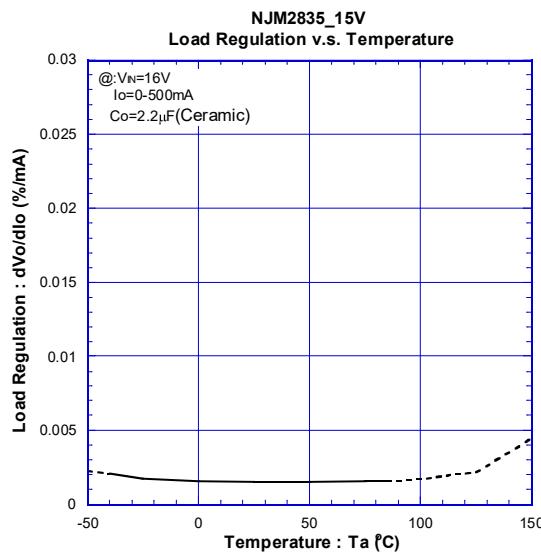
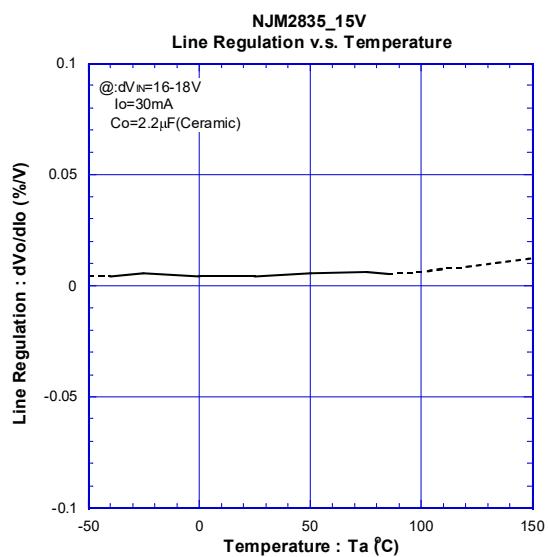
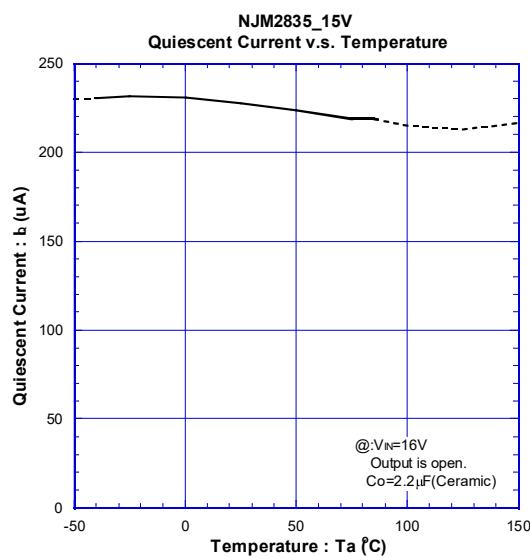
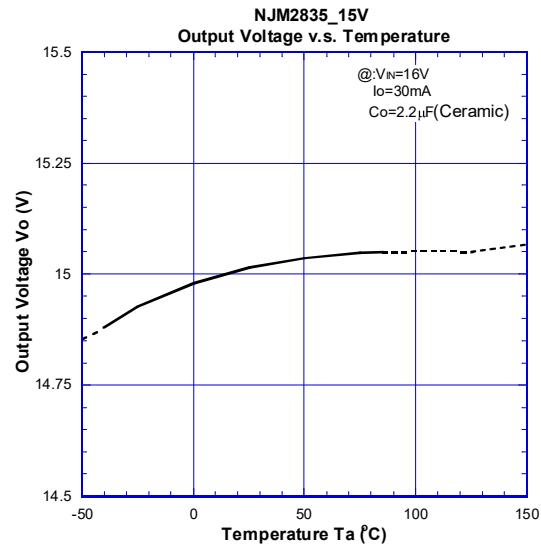
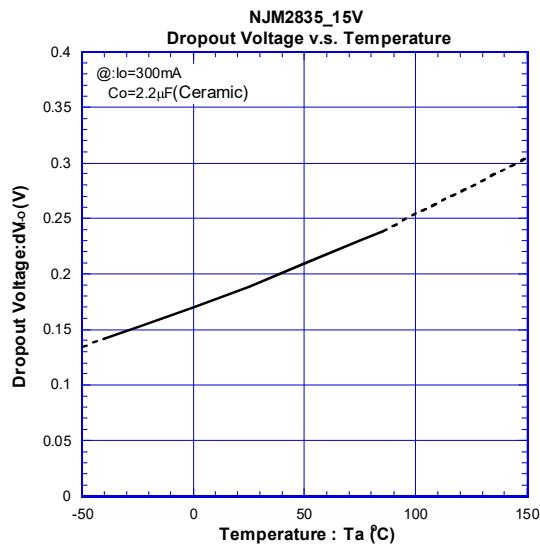


### • AC CHARACTERISTICS (15V Version)



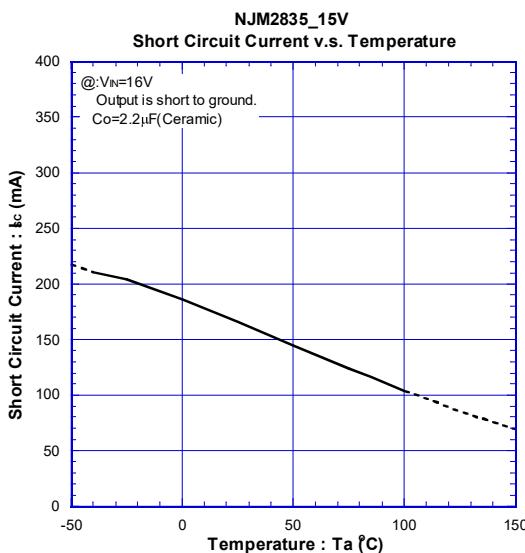
## ■ TYPICAL CHARACTERISTICS

### • TEMPERATURE CHARACTERISTICS (15V Version)



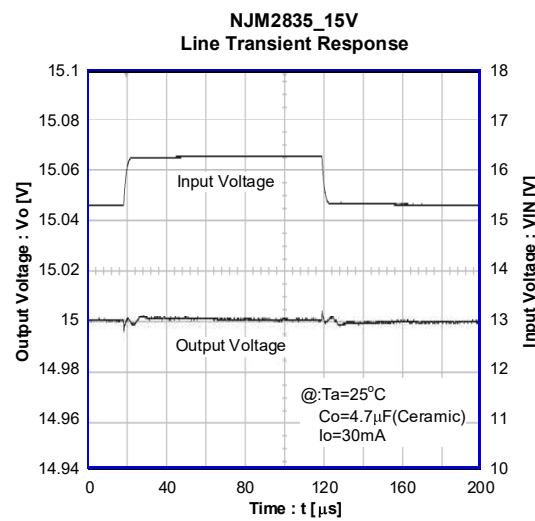
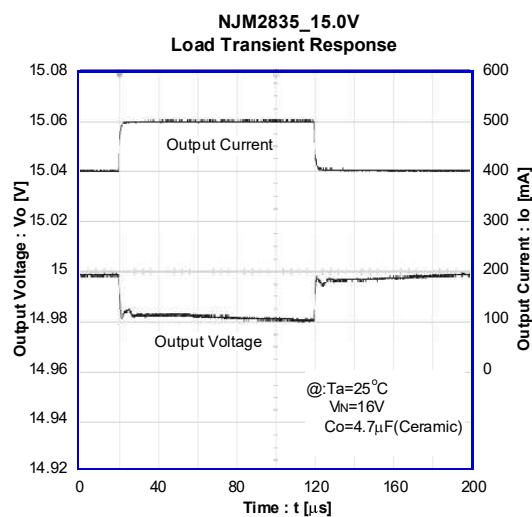
## ■ TYPICAL CHARACTERISTICS

### • TEMPERATURE CHARACTERISTICS (15V Version)



## ■ TYPICAL CHARACTERISTICS

### • TRANSIENT RESPONSE (15V Version)



[CAUTION]

The specifications on this databook are only given for information, without any guarantee as regards either mistakes or omissions. The application circuits in this databook are described only to show representative